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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	CANbus, I²C, SCI, SPI, USB OTG
Peripherals	LVD, PWM, WDT
Number of I/O	51
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf51jm64evlhr

1 MCF51JM128 Family Configurations

1.1 Device Comparison

The MCF51JM128 series consists of the devices compared in Table 1.

Table 1. MCF51JM128 Series Device Comparison

Feature	MCF51JM128			MCF51JM64			MCF51JM32		
	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin
Flash memory size (KB)	128			64			32		
RAM size (KB)	16			16			16		
V1 ColdFire core with BDM (background debug module)	Yes								
ACMP (analog comparator)	Yes								
ADC channels (12-bit)	12		8	12		8	12		8
CAN (controller area network)	Yes	Yes	No	Yes	Yes	No	Yes	Yes	No
RNGA + CAU	Yes[1]								
CMT (carrier modulator timer)	Yes								
COP (computer operating properly)	Yes								
IIC1 (inter-integrated circuit)	Yes								
IIC2	Yes	No		Yes	No		Yes	No	
IRQ (interrupt request input)	Yes								
KBI (keyboard interrupts)	8	8	6	8	8	6	8	8	6
LVD (low-voltage detector)	Yes								
MCG (multipurpose clock generator)	Yes								
Port I/O[2]	66	51	33	66	51	33	66	51	33
RGPIO (rapid general-purpose I/O)	16	6	0	16	6	0	16	6	0
RTC (real-time counter)	Yes								
SCI1 (serial communications interface)	Yes								
SCI2	Yes								
SPI1 (serial peripheral interface)	Yes								
SPI2	Yes								
TPM1 (timer/pulse-width modulator) channels	6	6	4	6	6	4	6	6	4
TPM2 channels	2								
USBOTG (USB On-The-Go dual-role controller)	Yes								
XOSC (crystal oscillator)	Yes								

1 Only existed on special part number

1.3 Features

Table 2 describes the functional units of the MCF51JM128 series.

Table 2. MCF51JM128 Series Functional Units

Unit	Function
CF1CORE (V1 ColdFire core)	Executes programs and interrupt handlers
BDM (background debug module)	Provides a single-pin debugging interface (part of the V1 ColdFire core)
DBG (debug)	Provides debugging and emulation capabilities (part of the V1 ColdFire core)
SYSCTL (system control)	Provides LVD, COP, external interrupt request, and so on
FLASH (flash memory)	Provides storage for program code and constants
RAM (random-access memory)	Provides storage for program code, constants, and variables
RGPIO (rapid general-purpose input/output)	Allows I/O port access at CPU clock speeds
VREG (voltage regulator)	Controls power management throughout the device
USBOTG (USB On-The-Go)	Supports the USB On-The-Go dual-role controller
ADC (analog-to-digital converter)	Measures analog voltages at up to 12 bits of resolution
TPM1, TPM2 (timer/pulse-width modulators)	Provide a variety of timing-based features
CF1_INTC (interrupt controller)	Controls and prioritizes all device interrupts
CAU (cryptographic acceleration unit)	Co-processor support for DES, 3DES, AES, MD5, and SHA-1
RNGA (random number generator accelerator)	32-bit random number generator that complies with FIPS-140
RTC (real-time counter)	Provides a constant-time base with optional interrupt
ACMP (analog comparator)	Compares two analog inputs
CMT (carrier modulator timer)	Infrared output used for the Remote Controller
IIC1, IIC2 (inter-integrated circuits)	Supports the standard IIC communications protocol
KBI (keyboard interrupt)	Provides pin interrupt capabilities
MCG (multipurpose clock generator)	Provides clocking options for the device, including a phase-locked loop (PLL) and frequency-locked loop (FLL) for multiplying slower reference clock sources
XOSC (crystal oscillator)	Supports low/high range crystals
CAN (controller area network)	Supports standard CAN communications protocol
SCI1, SCI2 (serial communications interfaces)	Serial communications UARTs that can support RS-232 and LIN protocols
SPI1, SPI2 (serial peripheral interfaces)	Provide a 4-pin synchronous serial interface

- Controller area network (MSCAN)
  - Implementation of the CAN protocol — Version 2.0A/B
  - Five receive buffers with FIFO storage scheme
  - Three transmit buffers with internal prioritization using a “local priority” concept
  - Flexible maskable identifier filter programmable as 2x32-bit, 4x16-bit, or 8x8-bit
  - Programmable wakeup functionality with integrated low-pass filter
  - Programmable loopback mode supports self-test operation
  - Programmable bus-off recovery functionality
  - Internal timer for time-stamping of received and transmitted messages
- Cryptographic acceleration unit (CAU)
  - Co-processor support of DES, 3DES, AES, MD5, and SHA-1
- Random number generator accelerator (RNGA)
  - 32-bit random number generator that complies with FIPS-140
- Analog-to-digital converter (ADC)
  - 12-channel, 12-bit resolution
  - Output formatted in 12-, 10-, or 8-bit right-justified format
  - Single or continuous conversion, and selectable asynchronous hardware conversion trigger
  - Operation in Stop3 mode
  - Automatic compare function
  - Internal temperature sensor
- Analog comparators (ACMP)
  - Selectable interrupt on rising edge, falling edge, or either rising or falling edges of comparator output
  - Option to compare to fixed internal bandgap reference voltage
  - Option to route output to TPM module
  - Operation in Stop3 mode
- Inter-integrated circuit (IIC)
  - Up to 100 kbps with maximum bus loading
  - Multi-master operation
  - Programmable slave address
  - Supports broadcast mode and 10-bit address extension
- Serial communications interfaces (SCI)
  - Two SCIs with full-duplex, non-return-to-zero (NRZ) format
  - LIN master extended break generation
  - LIN slave extended break detection
  - Programmable 8-bit or 9-bit character length
  - Wake up on active edge
- Serial peripheral interfaces (SPI)
  - Two serial peripheral interfaces with full-duplex or single-wire bidirectional
  - Double-buffered transmit and receive
  - Programmable transmit bit rate, phase, polarity, and Slave Select output
  - MSB-first or LSB-first shifting
- Timer/pulse width modulator (TPM)
  - 16-bit free-running or modulo up/down count operation
  - Up to eight channels, where each channel can be an input capture, output compare, or edge-aligned PWM
  - One interrupt per channel plus terminal count interrupt

Figure 4 shows the pinout of the 44-pin LQFP.

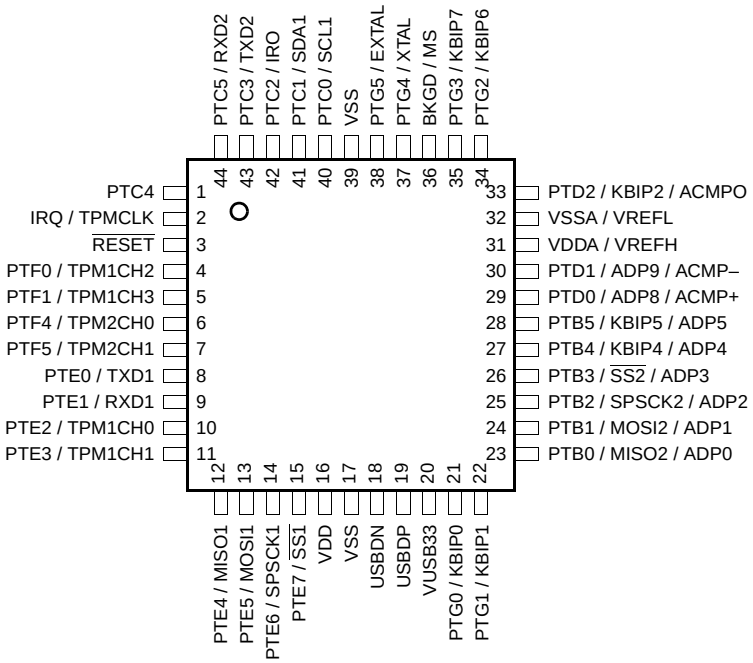


Figure 4. 44-pin LQFP

Table 4 shows the package pin assignments.

Table 4. Pin Assignments by Package and Pin Sharing Priority

Pin Number			<-- Lowest **Priority** --> Highest		
80	**64**	**44**	**Port Pin**	**Alt 1**	**Alt 2**
1	1	1	PTC4		—
2	2	2	—	IRQ	TPMCLK
3	3	3	—	$\overline{\text{RESET}}$	—
4	4	4	PTF0	TPM1CH2	—
5	5	5	PTF1	TPM1CH3	—
6	6	—	PTF2	TPM1CH4	—
7	7	—	PTF3	TPM1CH5	—
8	8	6	PTF4	TPM2CH0	BUSCLK_OUT
9	9	—	PTC6	RXCAN	—
10	10	—	PTF7	TXCAN	—
11	11	7	PTF5	TPM2CH1	—
12	12	—	PTF6	—	—
13	13	8	PTE0	TXD1	—
14	14	9	PTE1	RXD1	—
15	15	10	PTE2	TPM1CH0	—

Table 4. Pin Assignments by Package and Pin Sharing Priority (continued)

Pin Number			<-- Lowest **Priority** --> Highest		
80	**64**	**44**	**Port Pin**	**Alt 1**	**Alt 2**
16	16	11	PTE3	TPM1CH1	—
17	—	—	PTC7	—	—
18	—	—	PTH0	SDA2	—
19	—	—	PTH1	SCL2	—
20	—	—	PTH2	RGPIO8	—
21	—	—	PTH3	RGPIO9	—
22	—	—	PTH4	RGPIO10	—
23	17	12	PTE4	MISO1	—
24	18	13	PTE5	MOSI1	—
25	19	14	PTE6	SPSCK1	—
26	20	15	PTE7	$\overline{SS1}$	—
27	21	16	—	—	VDD
28	22	17	—	—	VSS
29	23	18	—	—	USBDN
30	24	19	—	—	USBDP
31	25	20	—	—	VUSB33
32	26	21	PTG0	KBIP0	USB_ALT_CLK
33	27	22	PTG1	KBIP1	—
34	28	—	PTA0	RGPIO0	USB_SESSVLD
35	29	—	PTA1	RGPIO1	USB_SESSEND
36	30	—	PTA2	RGPIO2	USB_VBUSVLD
37	31	—	PTA3	RGPIO3	USB_PULLUP(D+)
38	32	—	PTA4	RGPIO4	USB_DM_DOWN
39	33	—	PTA5	RGPIO5	USB_DP_DOWN
40	—	—	PTA6	RGPIO6	USB_ID
41	—	—	PTA7	RGPIO7	—
42	34	23	PTB0	MISO2	ADP0
43	35	24	PTB1	MOSI2	ADP1
44	36	25	PTB2	SPSCK2	ADP2
45	37	26	PTB3	$\overline{SS2}$	ADP3
46	38	27	PTB4	KBIP4	ADP4
47	39	28	PTB5	KBIP5	ADP5
48	40	—	PTB6	ADP6	—

Table 6. Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	V_{DD}	–0.3 to + 5.8	V
Input voltage	V_{In}	– 0.3 to V_{DD} + 0.3	V
Instantaneous maximum current Single pin limit (applies to all port pins)[1, 2, 3]	I_D	± 25	mA
Maximum current into V_{DD}	I_{DD}	120	mA
Storage temperature	T_{stg}	–55 to +150	°C
Maximum junction temperature	T_J	150	°C

1 Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.

2 All functional non-supply pins are internally clamped to V_{SS} and V_{DD}.

3 Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD}, the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load shunt current is greater than maximum injection current. This is the greatest risk when the MCU is not consuming power. Examples: if no system clock is present or if the clock rate is low, which would reduce overall power consumption.

2.3 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and it is user-determined rather than being controlled by the MCU design. To take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} is small.

Table 7. Thermal Characteristics

Rating		Symbol	Value	Unit
Operating temperature range (packaged)		T_A	–40 to +105	°C
Thermal resistance [1,2,3,4]				
80-pin LQFP				
	1s		52	
	2s2p		40	
64-pin LQFP				
	1s		65	
	2s2p	θ_{JA}	47	°C/W
64-pin QFP				
	1s		54	
	2s2p		40	
44-pin LQFP				
	1s		69	
	2s2p		48	

1 Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

2 Junction to Ambient Natural Convection

Table 9. ESD and Latch-Up Protection Characteristics

Num	Rating	Symbol	Min	Max	Unit
1	Human Body Model (HBM)	V_{HBM}	+/– 2000	—	V
2	Charge Device Model (CDM)	V_{CDM}	+/– 500	—	V
3	Latch-up Current at T_A = 105°C	I_{LAT}	+/– 100	—	mA

2.5 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 10. DC Characteristics

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
1		Operating voltage[2]		2.7	—	5.5	V
2	P	Output high voltage — Low Drive (PTxDSn = 0) 5 V, I_{Load} = –4 mA 3 V, I_{Load} = –2 mA 5 V, I_{Load} = –2 mA 3 V, I_{Load} = –1 mA	V_{OH}	 V_{DD} – 1.5 V_{DD} – 1.5 V_{DD} – 0.8 V_{DD} – 0.8	 — — — —	 — — — —	V
		Output high voltage — High Drive (PTxDSn = 1) 5 V, I_{Load} = –15 mA 3 V, I_{Load} = –8 mA 5 V, I_{Load} = –8 mA 3 V, I_{Load} = –4 mA		 V_{DD} – 1.5 V_{DD} – 1.5 V_{DD} – 0.8 V_{DD} – 0.8	 — — — —	 — — — —	
3	P	Output low voltage — Low Drive (PTxDSn = 0) 5 V, I_{Load} = 4mA 3 V, I_{Load} = 2 mA 5 V, I_{Load} = 2 mA 3 V, I_{Load} = 1 mA	V_{OL}		 — — — —	 1.5 1.5 0.8 0.8	V
		Output low voltage — High Drive (PTxDSn = 1) 5 V, I_{Load} = 15 mA 3 V, I_{Load} = 8 mA 5 V, I_{Load} = 8 mA 3 V, I_{Load} = 4 mA			 — — — —	 1.5 1.5 0.8 0.8	
4	P	Output high current — Max total I_{OH} for all ports 5V 3V	I_{OHT}	 — —	 — —	 100 60	mA
5	P	Output low current — Max total I_{OL} for all ports 5V 3V	I_{OLT}	 — —	 — —	 100 60	mA
6	P	Input high voltage; all digital inputs	V_{IH}				V
		V_{DD} = 5V V_{DD} = 3V		3.25 2.10	— —	— —	

Table 10. DC Characteristics (continued)

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
7	P	Input low voltage; all digital inputs V_{DD} = 5V V_{DD} = 3V	V_{IL}	—	—	 1.75 1.05	V
8	P	Input hysteresis; all digital inputs	V_{hys}	0.06 x V_{DD}			mV
9	P	Input leakage current; input only pins[3]	$\|I_{In}\|$	—	0.1	1	µA
10	P	High Impedance (off-state) leakage current[3]	$\|I_{OZ}\|$	—	0.1	1	µA
11	P	Internal pullup resistors[4]	R_{PU}	20	45	65	kΩ
12	P	Internal pulldown resistors[5]	R_{PD}	20	45	65	kΩ
13		Internal pullup resistor to USBDP (to V_{USB33}) Idle Transmit	R_{PUPD}	 900 1425	 1300 2400	 1575 3090	kΩ
14	C	Input Capacitance; all non-supply pins	C_{In}	—	—	8	pF
15	D	RAM retention voltage[6]	V_{RAM}	—	0.6	1.0	V
16	P	POR rearm voltage	V_{POR}	0.9	1.4	2.0	V
17	D	POR rearm time	t_{POR}	10	—	—	µs
18	P	Low-voltage detection threshold — high range V_{DD} falling V_{DD} rising	V_{LVD1}	 3.9 4.0	 4.0 4.1	 4.1 4.2	V
19	P	Low-voltage detection threshold — low range V_{DD} falling V_{DD} rising	V_{LVD0}	 2.48 2.54	 2.56 2.62	 2.64 2.70	V
20	C	Low-voltage warning threshold — high range 1 V_{DD} falling V_{DD} rising	V_{LVW3}	 4.5 4.6	 4.6 4.7	 4.7 4.8	V
21	P	Low-voltage warning threshold — high range 0 V_{DD} falling V_{DD} rising	V_{LVW2}	 4.2 4.3	 4.3 4.4	 4.4 4.5	V
22	P	Low-voltage warning threshold low range 1 V_{DD} falling V_{DD} rising	V_{LVW1}	 2.84 2.90	 2.92 2.98	 3.00 3.06	V
23	C	Low-voltage warning threshold — low range 0 V_{DD} falling V_{DD} rising	V_{LVW0}	 2.66 2.72	 2.74 2.80	 2.82 2.88	V
24	T	Low-voltage inhibit reset/recover hysteresis 5 V 3 V	V_{hys}	 — —	 100 60	 — —	mV

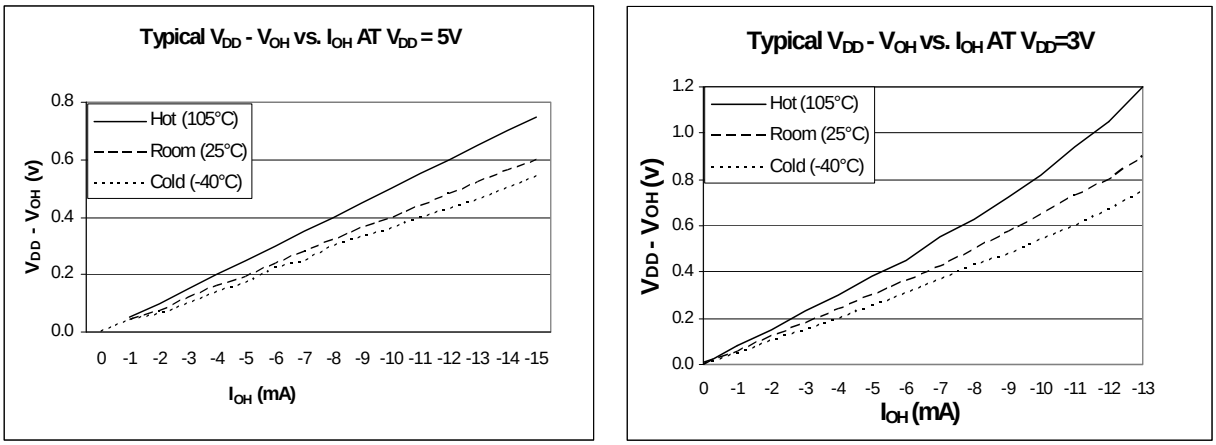


Figure 7. Typical High-side Drive (source) characteristics – High Drive (PTxDSn = 1)

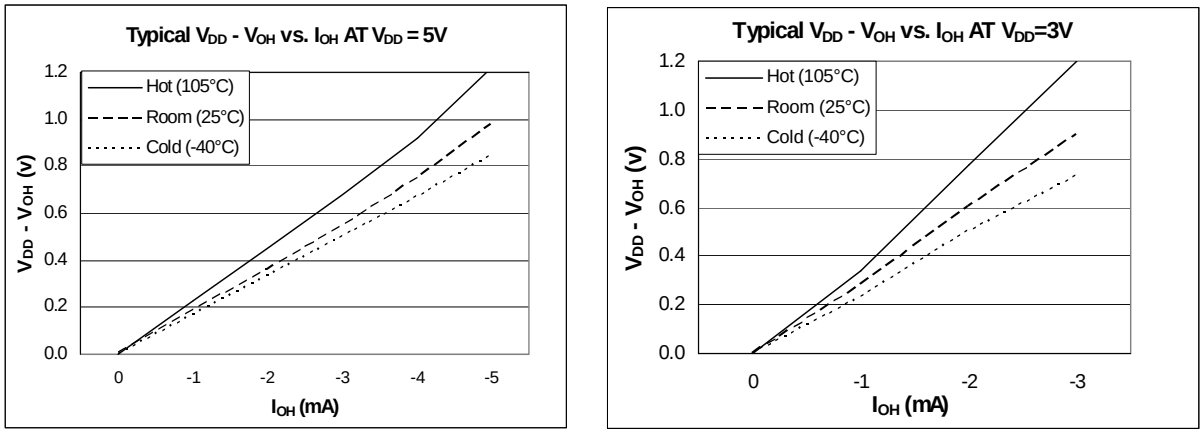


Figure 8. Typical High-side Drive (source) characteristics – Low Drive (PTxDSn = 0)

2.6 Supply Current Characteristics

Table 11. Supply Current Characteristics

Num	C	Parameter	Symbol	V_{DD} (V)	Typical[1]	Max[2]	Unit
1	C	Run supply current[3] measured at (CPU clock = 2 MHz, f_{Bus} = 1 MHz)	RI_{DD}	5	4.0	7	mA
				3	4.0	7	
2	P	Run supply current[3] measured at (CPU clock = 16 MHz, f_{Bus} = 8 MHz)		5	19	30	mA
				3	18.7	30	
3	C	Run supply current[3] measured at (CPU clock = 48 MHz, f_{Bus} = 24 MHz)		5	45	70	mA
				3	44	70	

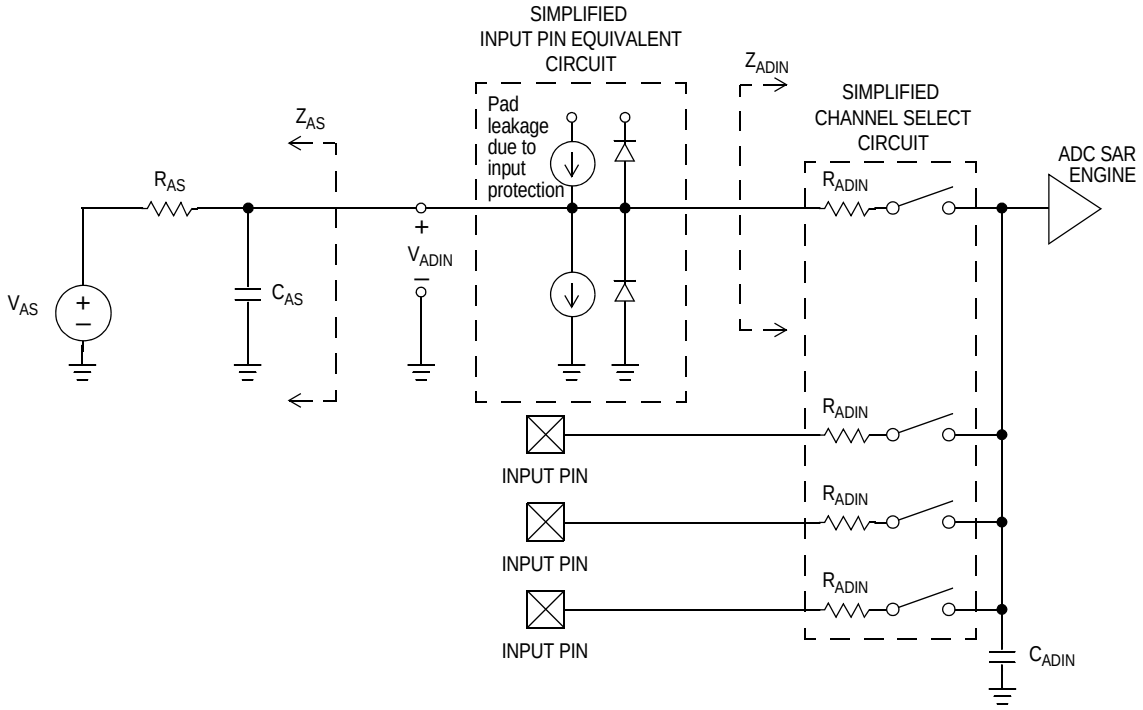


Figure 9. ADC Input Impedance Equivalency Diagram

Table 14. 5 Volt 12-bit ADC Characteristics (V_{REFH} = V_{DDA}, V_{REFL} = V_{SSA})

Characteristic	Conditions	C	Symb	Min	Typ[1]	Max	Unit	Comment
Supply Current ADLPC=1 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	133	—	µA	
Supply Current ADLPC=1 ADLSMP=0 ADCO=1		T	I_{DDAD}	—	218	—	µA	
Supply Current ADLPC=0 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	327	—	µA	
Supply Current ADLPC=0 ADLSMP=0 ADCO=1		P	I_{DDAD}	—	0.582	1	mA	
Supply Current	Stop, Reset, Module Off		I_{DDAD}	—	0.011	1	µA	
ADC Asynchronous Clock Source	High Speed (ADLPC=0)	T	f_{ADACK}	2	3.3	5	MHz	t_{ADACK} = $1/f_{ADACK}$
	Low Power (ADLPC=1)			1.25	2	3.3		

2.9 External Oscillator (XOSC) Characteristics

Table 15. Oscillator Electrical Specifications (Temperature Range = –40 to 105°C Ambient)

Num	C	Rating	Symbol	Min	Typ[1]	Max	Unit
1		Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) • Low range (RANGE = 0) • High range (RANGE = 1) FEE or FBE mode [2] • High range (RANGE = 1) PEE or PBE mode [3] • High range (RANGE = 1, HGO = 1) BLPE mode • High range (RANGE = 1, HGO = 0) BLPE mode	 f_{lo} $f_{hi\text{-}fll}$ $f_{hi\text{-}pll}$ $f_{hi\text{-}hgo}$ $f_{hi\text{-}lp}$	 32 1 1 1 1	 — — — — —	 38.4 5 16 16 8	 kHz MHz MHz MHz MHz
2		Load capacitors	C_1 C_2	See crystal or resonator manufacturer's recommendation.			
3		Feedback resistor • Low range (32 kHz to 38.4 kHz) • High range (1 MHz to 16 MHz)	R_F		10 1		MΩ MΩ
4	—	Series resistor • Low range, low gain (RANGE = 0, HGO = 0) • Low range, high gain (RANGE = 0, HGO = 1) ≥ 8 MHz 4 MHz 1 MHz • High range, low gain (RANGE = 1, HGO = 0) • High range, high gain (RANGE = 1, HGO = 1) ≥ 8 MHz 4 MHz 1 MHz	R_S	 — — — — — —	 0 100 0 0 0 0	 — — — 0 10 20	kΩ
5	T	Crystal start-up time [4] • Low range, low gain (RANGE = 0, HGO = 0) • Low range, high gain (RANGE = 0, HGO = 1) • High range, low gain (RANGE = 1, HG0 = 0)[5] • High range, high gain (RANGE = 1, HG0 = 1)[5]	 $t_{CSTL\text{-}LP}$ $t_{CSTL\text{-}HGO}$ $t_{CSTH\text{-}LP}$ $t_{CSTH\text{-}HGO}$	 — — — —	 200 400 5 15	 — — — —	ms
6	T	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) • FEE or FBE mode [2] • PEE or PBE mode [3] • BLPE mode	f_{extal}	0.03125 1 0	— — —	5 16 40	MHz MHz MHz

1 Data in Typical column was characterized at 5.0 V, 25°C or is typical recommended value.

2 When MCG is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.

3 When MCG is configured for PEE or PBE mode, input clock source must be divisible using RDIV to within the range of 1 MHz to 2 MHz.

4 This parameter is characterized and not tested on each device. Proper PC board-layout procedures must be followed to achieve specifications.

5 4 MHz crystal

5 Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{BUS}. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via V_{DD} and V_{SS} and variation in crystal oscillator frequency increase the C_{Jitter} percentage for a given interval.

6 625 ns represents 5 time quanta for CAN applications, under worst case conditions of 8 MHz CAN bus clock, 1 Mbps CAN bus speed, and 8 time quanta per bit for bit time settings. 5 time quanta is the minimum time between a synchronization edge and the sample point of a bit using 8 time quanta per bit.

7 Below D_{lock} minimum, the MCG is guaranteed to enter lock. Above D_{lock} maximum, the MCG will not enter lock. But if the MCG is already in lock, then the MCG may stay in lock.

8 Below D_{unl} minimum, the MCG will not exit lock if already in lock. Above D_{unl} maximum, the MCG is guaranteed to exit lock.

2.11 AC Characteristics

This section describes ac timing characteristics for each peripheral system.

2.11.1 Control Timing

Table 17. Control Timing

Num	C	Parameter	Symbol	Min	Typ[1]	Max	Unit
1		Bus frequency ($t_{cyc} = 1/f_{Bus}$)	f_{Bus}	dc	—	24	MHz
2		Internal low-power oscillator period	t_{LPO}	700		1300	µs
3		External reset pulse width[2] ($t_{cyc} = 1/f_{Self\_reset}$)	t_{extrst}	100		—	ns
4		Reset low drive	t_{rstdrv}	66 x t_{cyc}		—	ns
5		Active background debug mode latch setup time	t_{MSSU}	500		—	ns
6		Active background debug mode latch hold time	t_{MSH}	100		—	ns
7		IRQ pulse width Asynchronous path[2] Synchronous path[3]	t_{ILIH}, t_{IHIL}	 100 1.5 x t_{cyc}	—	—	ns
8		KBIPx pulse width Asynchronous path[2] Synchronous path[3]	t_{ILIH}, t_{IHIL}	 100 1.5 x t_{cyc}	—	—	ns
9		Port rise and fall time (load = 50 pF)[4] Slew rate control disabled (PTxSE = 0) High drive Slew rate control enabled (PTxSE = 1) High drive Slew rate control disabled (PTxSE = 0) Low drive Slew rate control enabled (PTxSE = 1) Low drive	t_{Rise}, t_{Fall}	 — — 	 11 35 40 75		ns

1 Typical values are based on characterization data at V_{DD} = 5.0V, 25°C unless otherwise stated.

2 This is the shortest pulse guaranteed to be recognized as a reset pin request. Shorter pulses are not guaranteed to override reset requests from internal sources.

3 This is the minimum pulse width guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized in that case.

4 Timing is shown with respect to 20% V_{DD} and 80% V_{DD} levels. Temperature range –40°C to 105°C.

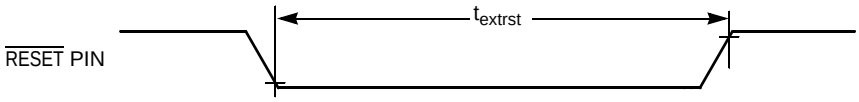


Figure 10. Reset Timing

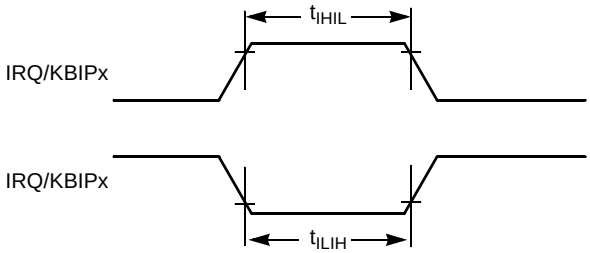


Figure 11. IRQ/KBIPx Timing

2.11.2 Timer/PWM (TPM) Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 18. TPM Input Timing

NUM	C	Function	Symbol	Min	Max	Unit
1	—	External clock frequency	f_{TPMext}	dc	$f_{Bus}/4$	MHz
2	—	External clock period	t_{TPMext}	4	—	t_{cyc}
3	D	External clock high time	t_{clkh}	1.5	—	t_{cyc}
4	D	External clock low time	t_{clkl}	1.5	—	t_{cyc}
5	D	Input capture pulse width	t_{ICPW}	1.5	—	t_{cyc}

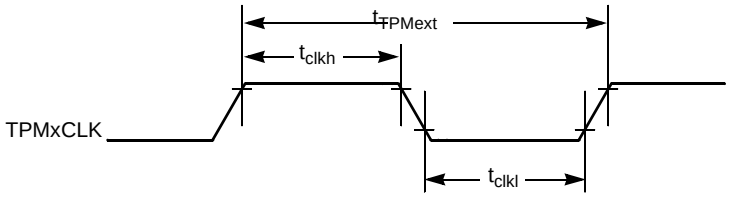
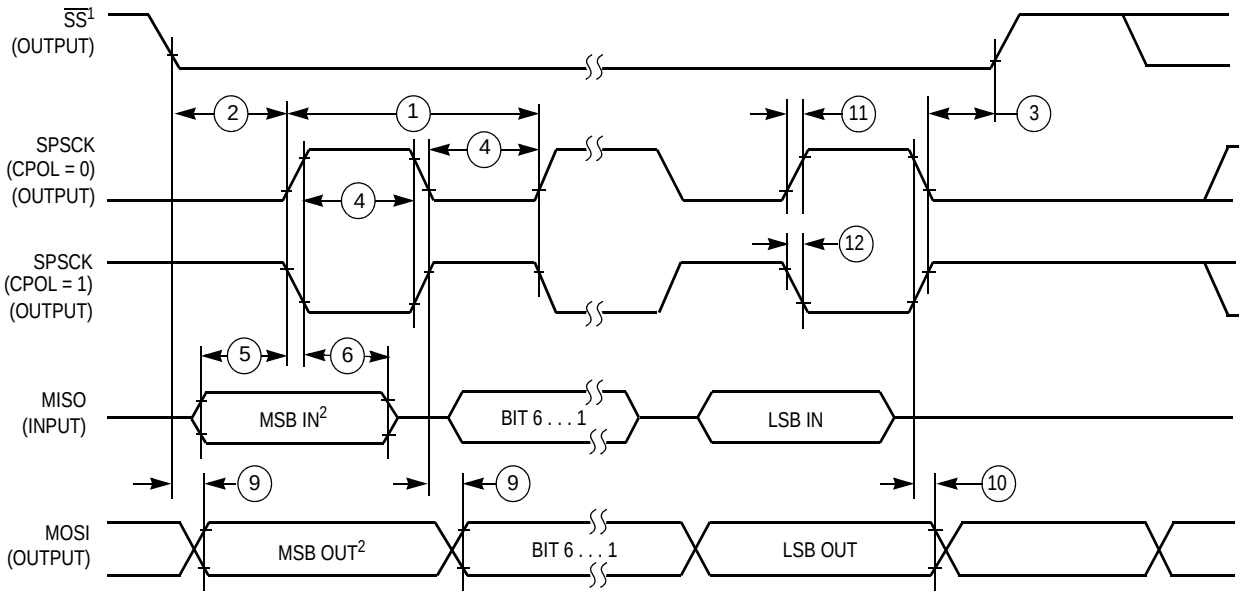


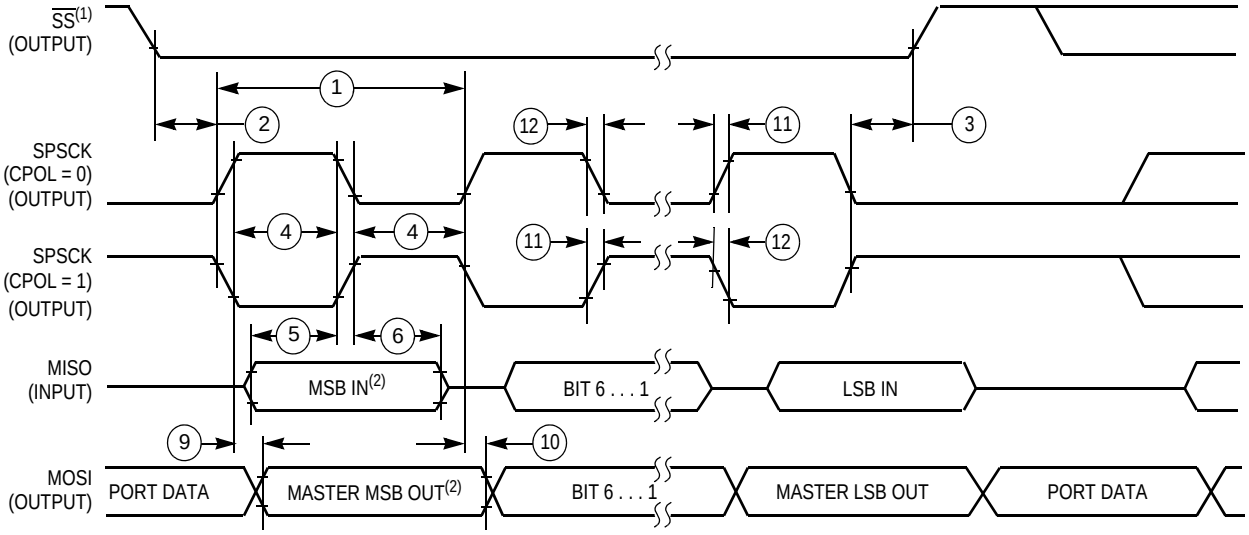
Figure 12. Timer External Clock



NOTES:

1. $\overline{SS}$ output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

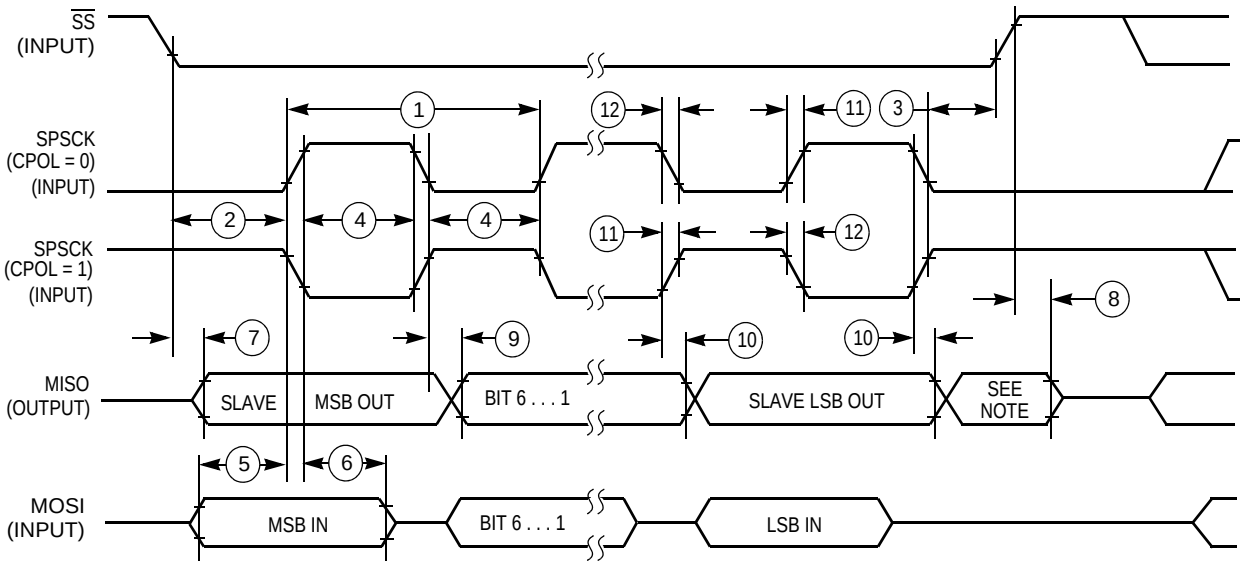
Figure 14. SPI Master Timing (CPHA = 0)



NOTES:

1. $\overline{SS}$ output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

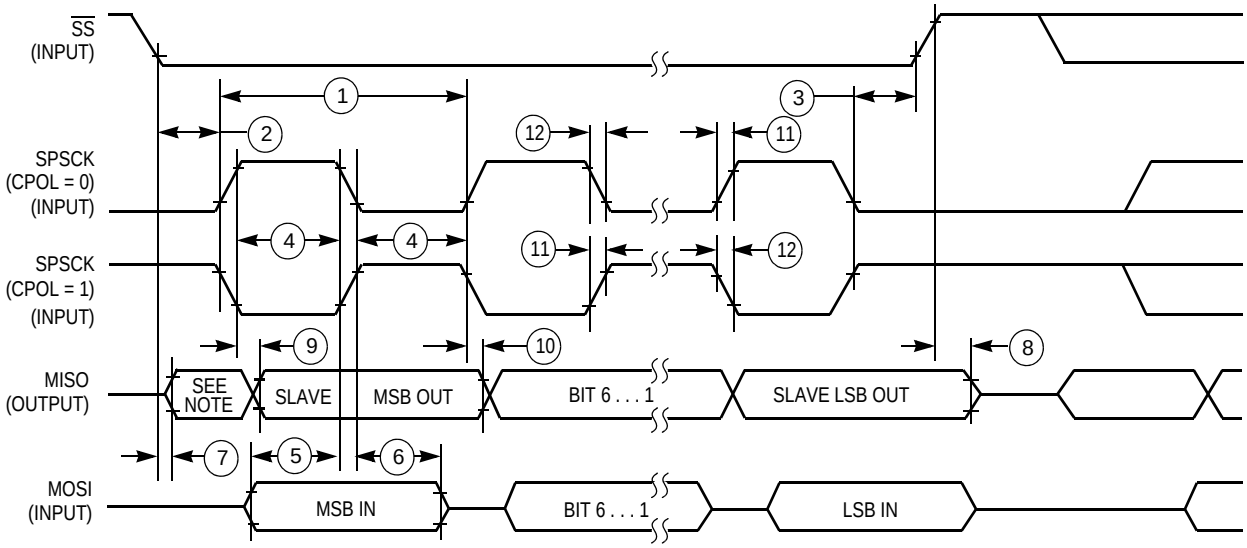
Figure 15. SPI Master Timing (CPHA = 1)



NOTE:

1. Not defined but normally MSB of character just received

Figure 16. SPI Slave Timing (CPHA = 0)



NOTE:

1. Not defined but normally LSB of character just received

Figure 17. SPI Slave Timing (CPHA = 1)

2.13 Flash Specifications

This section provides details about program/erase times and program-erase endurance for the Flash memory.

Program and erase operations do not require any special power sources other than the normal V_{DD} supply.

Table 21. Flash Characteristics

Num	C	Characteristic	Symbol	Min	Typ[1]	Max	Unit
1		Supply voltage for program/erase	$V_{prog/erase}$	2.7		5.5	V
2		Supply voltage for read operation	V_{Read}	2.7		5.5	V
3		Internal FCLK frequency[2]	f_{FCLK}	150		200	kHz
4		Internal FCLK period (1/FCLK)	t_{Fcyc}	5		6.67	µs
5		Byte program time (random location)(2)	t_{prog}	9			t_{Fcyc}
6		Byte program time (burst mode)(2)	t_{Burst}	4			t_{Fcyc}
7		Page erase time[3]	t_{Page}	4000			t_{Fcyc}
8		Mass erase time(2)	t_{Mass}	20,000			t_{Fcyc}
9	C	Program/erase endurance[4] T_L to T_H = –40°C to + 105°C T = 25°C		10,000 —	— 100,000	— —	cycles
10		Data retention[5]	t_{D_ret}	15	100	—	years

1 Typical values are based on characterization data at V_{DD} = 5.0 V, 25°C unless otherwise stated.

2 The frequency of this clock is controlled by a software setting.

3 These values are hardware state machine controlled. User code does not need to count cycles. This information supplied for calculating approximate time to program and erase.

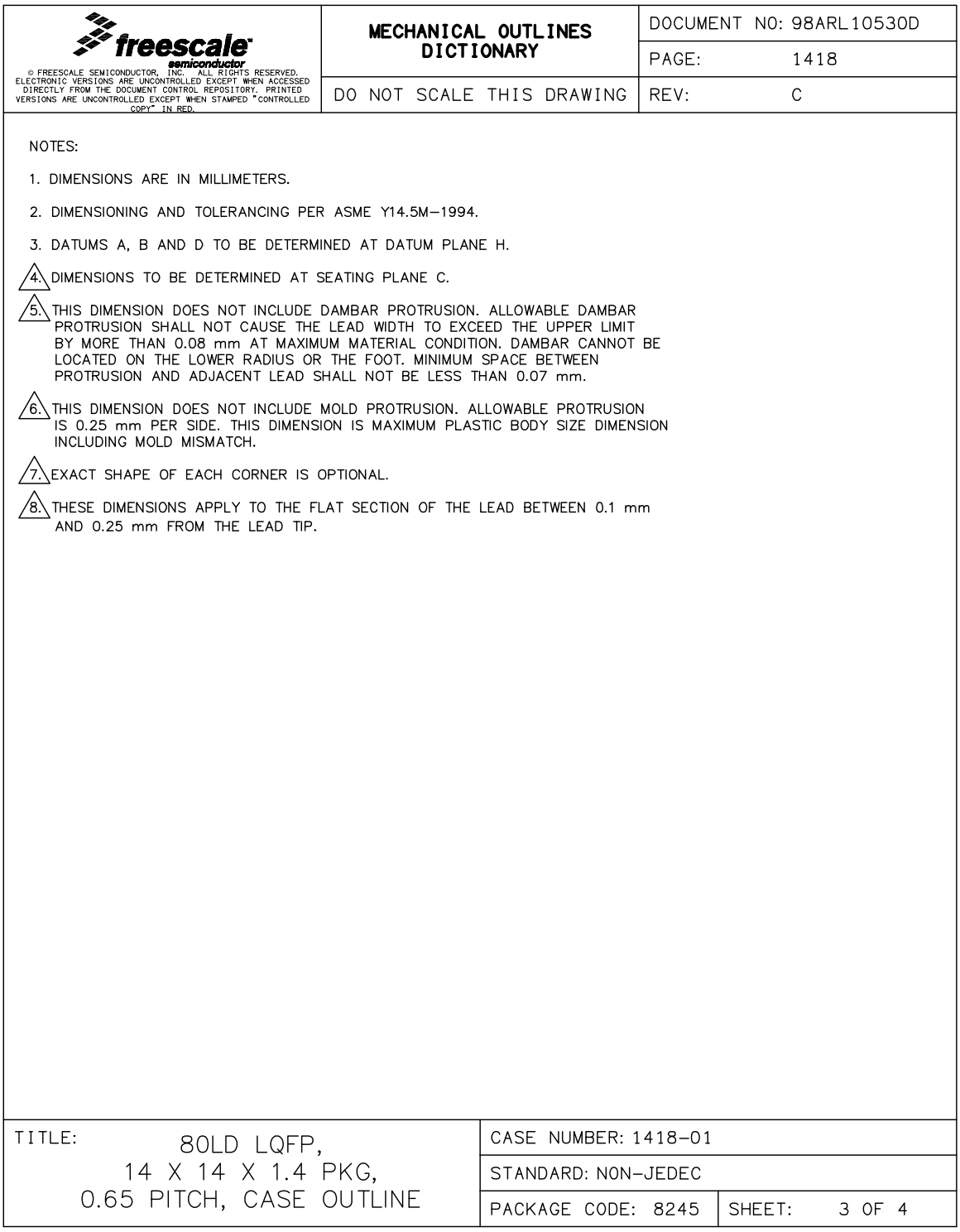
4 Typical endurance for Flash was evaluated for this product family on the 9S12Dx64. For additional information on how Freescale Semiconductor defines typical endurance, please refer to Engineering Bulletin EB619/D, *Typical Endurance for Nonvolatile Memory*.

5 Typical data retention values are based on intrinsic capability of the technology measured at high temperature and de-rated to 25°C using the Arrhenius equation. For additional information on how Freescale Semiconductor defines typical data retention, please refer to Engineering Bulletin EB618/D, Typical Data Retention for Nonvolatile Memory.

2.14 USB Electricals

The USB electricals for the USBOTG module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit http://www.usb.org.

If the Freescale USBOTG implementation requires additional or deviant electrical characteristics, this space would be used to communicate that information.



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MECHANICAL OUTLINES DICTIONARY

DOCUMENT NO: 98ARL10530D

PAGE: 1418

DO NOT SCALE THIS DRAWING

REV: C

NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

TITLE: 80LD LQFP, 14 X 14 X 1.4 PKG, 0.65 PITCH, CASE OUTLINE

CASE NUMBER: 1418–01

STANDARD: NON–JEDEC

PACKAGE CODE: 8245

SHEET: 3 OF 4

Figure 20. 80-pin LQFP Diagram - III

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		PAGE: 840B
	DO NOT SCALE THIS DRAWING	REV: B

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DATUM PLANE −H− IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE.
4. DATUMS A−B AND −D− TO BE DETERMINED AT DATUM PLANE −H−.
5. DIMENSIONS TO BE DETERMINED AT SEATING PLANE −C−.
6. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PER SIDE. DIMENSIONS DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE −H−.
7. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE DIMENSION AT MAXIMUM MATERIAL CONDICTION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT.

TITLE: 64LD QFP (14 X 14)	CASE NUMBER: 840B−01	
	STANDARD: NON−JEDEC	
	PACKAGE CODE: 6057	SHEET: 3 OF 4

Figure 26. 64-pin QFP Diagram - III

3.4 44-pin LQFP

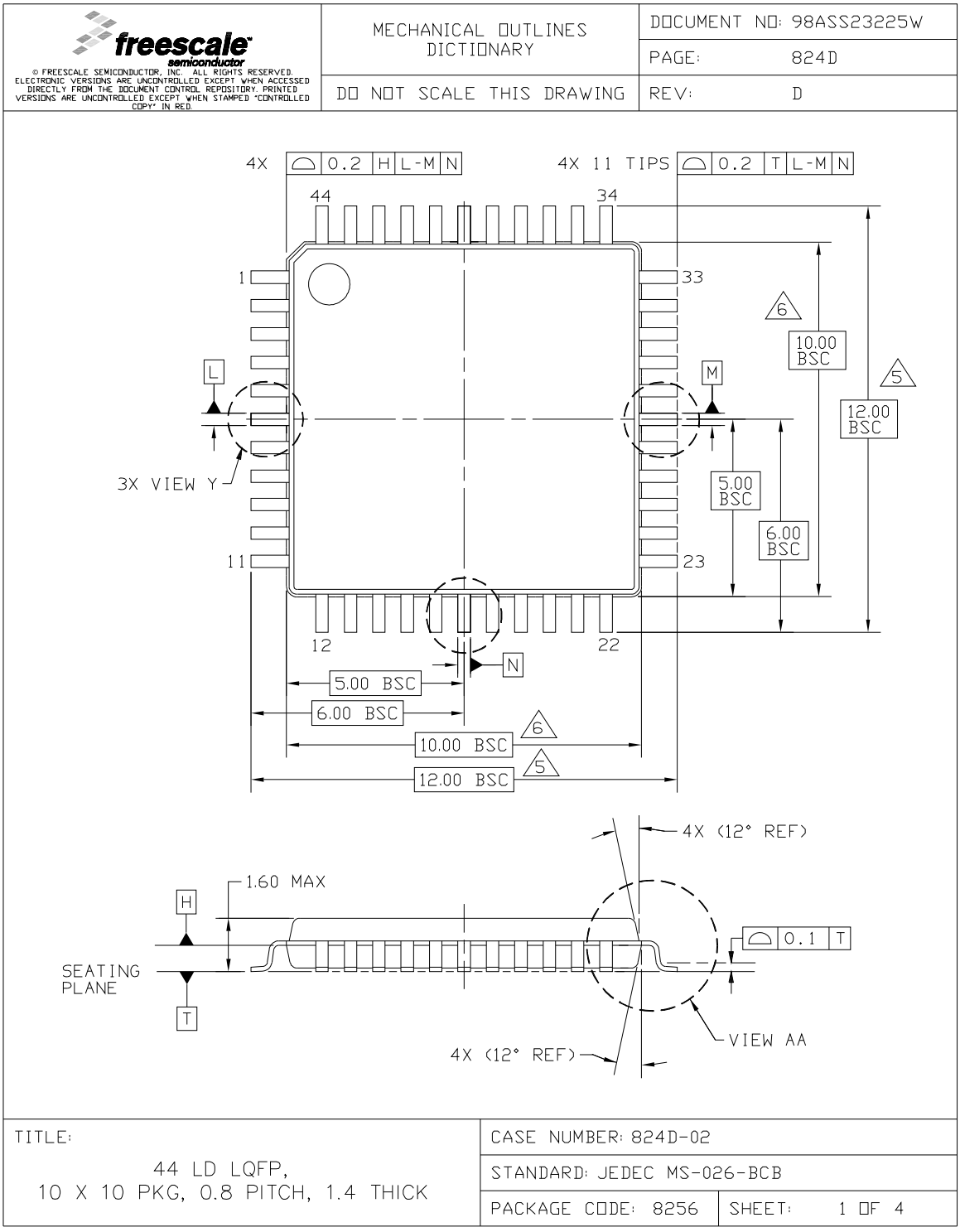

Figure 27. 44-pin LQFP Diagram - I

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Freescale Semiconductor, Inc.
Technical Information Center, EL516
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Tempe, Arizona 85284
1-800-521-6274 or +1-480-768-2130
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Europe, Middle East, and Africa:
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Technical Information Center
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81829 Muenchen, Germany
+44 1296 380 456 (English)
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Japan:
Freescale Semiconductor Japan Ltd. Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:
Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
Chaoyang District
Beijing 100022
China
+86 10 5879 8000
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